

# IMPLEMENTATION OF CASCADED HIGH STEP-UP DC-DC CONVERTER USING THREE-WINDING COUPLED INDUCTOR AND DIODE CAPACITOR TECHNIQUE

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**Abstract** –A cascaded high step up DC-DC converter realized with a tightly coupled three-winding coupled inductor is introduced in this paper. The capacitors are charged in parallel and discharged in series by the coupled inductor. Thus, the proposed converter can achieve high step-up voltage gain with appropriate duty ratio. The voltage stresses on the main switch can be reduced by a passive clamp circuit. Therefore, low resistance  $R_{DS(ON)}$  for main switch can be adopted to reduce conduction loss. Compared with existing high step up converters, the proposed converter features that the smaller the turn's ratio is, the larger the conversion gain. So, the name couple inductor reverse is given to represent reverse coupled inductor principle of operation. In addition, diode-capacitor circuit is introduced to not only recycle leakage energy to output, but also further increase the voltage conversion gain. The metal-oxide-semiconductor field-effect transistor (MOSFET) was used for the switching device. The major goal was to improve efficiency. The results of simulations are presented to evaluate the behavior and feasibility of the proposed topology. The operation of proposed system has been found satisfactory.

**Index Terms** - Cascaded high step-up DC-DC converter, coupled inductor-reverse, Metal-oxide-semiconductor field-effect transistor (MOSFET), Switching losses, reduced turns ratio.

## I.INTRODUCTION

Renewable energy is increasingly becoming a hot research topic, the high step-up converter is also widely employed as an interface in many industry applications, such as fuel cell system, photovoltaic system, electric vehicles, and so on. In general, conventional boost converter can satisfy the requirement in such applications [1]. To achieve a high conversion ratio without operating at large duty cycle, some papers have focused on coupled inductor technique. Typical isolated flyback converter is often adopted for achieving high voltage gain by adjusting the turns ratio [4]. But, the leakage inductance may cause high voltage spikes on the switch and induce energy losses. In order to improve the problems, passive snubber circuit or active clamp circuit can be applied. However, some typical drawbacks exist: The voltage stress of main switch is equal to the output voltage; hence, a high voltage rating switch with high on-resistance should be used, generating high conduction losses [7]. In addition, an extremely high duty ratio will induce large conduction losses on power devices and serious diode reverse recovery problem. Based on the above drawbacks, the conventional boost converter is not suitable for realizing high step-up voltage gain together with high efficiency. Many other techniques have been researched to achieve a high conversion ratio and avoid operating at extreme duty ratio such as switched capacitor technique [7], voltage lift technique [10] and so on. More components, however, are needed for extremely large conversion ratio, resulting in higher cost and complex circuit.

In the proposed strategy, a coupled inductor with a lower voltage rated switch is used for raising the voltage gain (whether the switch is turned on or turned off) [6]. The capacitors are charged in parallel and discharged in series by the coupled inductor, stacking on the output capacitor. Thus, the converter can achieve high step-up voltage gain with appropriate duty cycle [7]. Besides, the voltage spike on the main switch can be clamped. Therefore, low on-state resistance  $R_{DS(ON)}$  of the main switch can be adopted to reduce the conduction loss [8]. But, this makes both cost and circuit high and complex. However, under the condition of large voltage conversion gain, the turns ratio must be very high. Using a coupled inductor with a large turn ratio also introduces several problems [12]. For example, the leakage inductance and parasitic capacitance formed by secondary winding of the coupled inductor may cause voltage and current spikes and increase loss and noise that will dramatically degrade the system performance [9]. In this paper, a novel cascaded high step-up dc-dc converter with three-winding coupled inductor and diode-capacitor structures are proposed.

The features of the proposed converter are as follows [1]:

- 1) The smaller the turn's ratio is, the higher voltage conversion gain.

- 2) Leakage inductance energy can be recycled to the output,
- 3) The cascaded structure makes voltage conversion gain higher.

II. BASIC OPERATING PRINCIPLE:

Fig.1 shows the equivalent circuit of the coupled inductor. and Fig. 2 shows circuit structure of the proposed converter, which consists of three-winding coupled inductor, that is modeled as an ideal transformer with a turns ratio ( $N_2: N_1: N_3$ ), a magnetizing inductance  $L_M$ , and leakage inductances  $L_{k1}$ ,  $L_{k2}$ , and  $L_{k3}$ , a power switch  $S$ , an input inductor  $L_{in}$ , a three-winding coupled inductor, diodes  $D_1$ ,  $D_2$ ,  $D_3$ ,  $D_4$ , and  $D_0$ , a storage energy capacitor  $C_1$ , a clamped capacitor  $C_c$ , a multiplier capacitor  $C_2$ , and an output capacitor  $C_o$ . Equivalent circuit of the proposed converter is shown in Fig. 2(b).

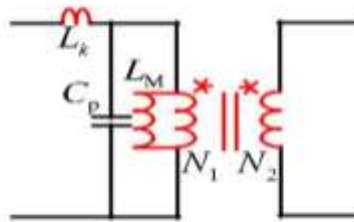


Fig.1.Equivalent circuit of the coupled inductor.

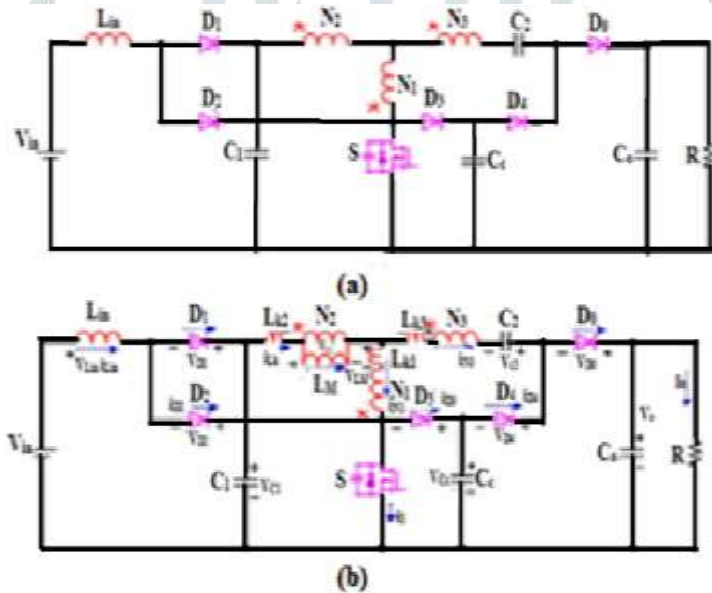


Fig.2 Circuit configuration of the proposed converter.

Fig. 8 shows theoretical waveforms of the proposed converter during one whole switching period. The five operating modes are described as follows.

- 1) Mode I [ $t_0, t_1$ ]: During this mode, the switch  $S$  is turned ON and starts to conduct. The diodes  $D_1$  and  $D_0$  are forward biased and  $D_2, D_3,$  and  $D_4$  are reverse biased. The current-flow path is shown in Fig. 3. The input voltage  $V_{in}$ , input inductor  $L_{in}$ , magnetizing inductance  $L_M$ , and multiplier capacitor  $C_2$  are in series to provide energies to the load  $R$  and output capacitor  $C_o$ . When the current  $i_{D_0}$  decreases to zero at  $t_1$ , this mode ends.

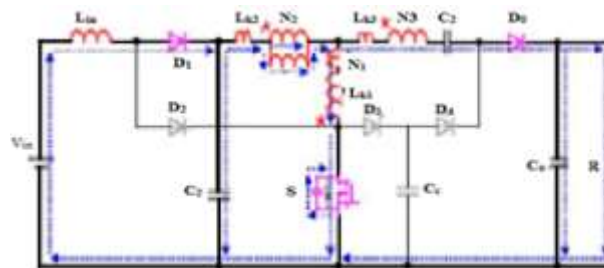


Fig.3

- 2) Mode II [ $t_1, t_2$ ]: During this mode, the switch S is turned ON and keeps conducting. The diodes  $D_2$  and  $D_4$  are forward biased and  $D_1, D_3,$  and  $D_0$  are reverse biased. The input inductor  $L_{in}$  is charged by input source  $V_{in}$ . The current-flow path is shown in Fig. 4. The windings of coupled inductor  $N_1$  and  $N_3$ ,  $C_c$  are in series to provide energy to the multiplier capacitor  $C_2$ . The output capacitor  $C_o$  provides energy to the load R. When the switch S is turned OFF at  $t_2$ , this mode ends.

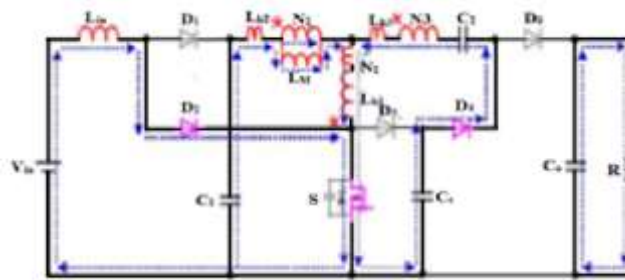


Fig.4

- 3) Mode III [ $t_2, t_3$ ]: During this mode, the switch S is turned OFF. The diodes  $D_2$  and  $D_4$  are forward biased and  $D_1, D_3,$  and  $D_0$  are reverse biased. The energies of leakage inductor  $L_{k2}$  and  $L_{k1}$ , magnetizing inductance  $L_M$  and input inductor  $L_{in}$  are released to the parasitic capacitor of switch S. Fig. 5 shows the current-flow path. The output capacitor  $C_o$  provides the energy to the load R. When the voltage stress across the parasitic capacitor of switch S is equal to the voltage stress across clamped capacitor  $C_c$  at  $t_3$ , this mode ends.

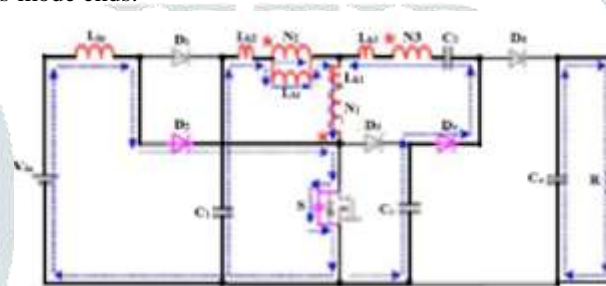


Fig.5

- 4) Mode IV [ $t_3, t_4$ ]: During this mode, the switch S is turned OFF. The diodes  $D_2$  and  $D_4$  are reverse biased and  $D_1, D_3$  and  $D_0$  are forward biased. The capacitor  $C_1$  is charged by the input source  $V_{in}$  and input inductor  $L_{in}$ . The clamped capacity or  $C_c$  is charged by the energies of leakage inductor  $L_{k2}, L_{k1}$ , and magnetizing inductance  $L_M$ . Fig. 6 shows the current-flow path. The input source  $V_{in}$ , input inductor  $L_{in}$ , magnetizing inductance  $L_M$ , and multiplier capacitor  $C_2$  are in series to provide energies to the load R and output capacitor  $C_o$ . When the charging current  $i_{D3}$  is equal to zero at  $t_4$ , this mode ends.

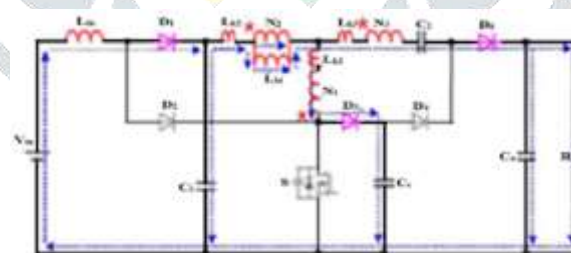


Fig.6

- 5) Mode V [ $t_4, t_5$ ]: During this mode also the switch S is OFF. The diodes  $D_2, D_3,$  and  $D_4$  are reverse biased and  $D_1$  and  $D_0$  are forward biased. The capacitor  $C_1$  is still charged by  $V_{in}$  and input inductor  $L_{in}$ . Fig. 7 shows the current-flow path. The input voltage  $V_{in}$ , input inductor  $L_{in}$ , magnetizing inductance  $L_M$ , and multiplier capacitor  $C_2$  are in series to provide energies to the load R and output capacitor  $C_o$ . When the switch S begins to conduct at  $t_5$ , next switching period begins.

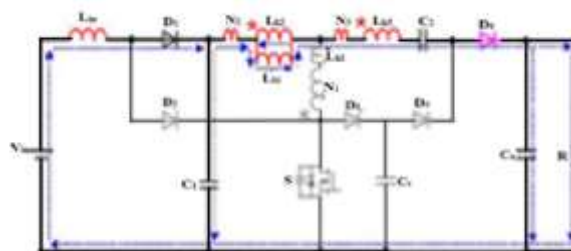


Fig. 7

Advantage:

In the proposed converter, voltage gain formula is different from other converters. The voltage gain formula combines both square feature and inverse ratio feature of the turns ratio. The two features can reduce the duty cycle, winding turns, voltage stress, and coupled inductor volume and so on when operating at the same condition.

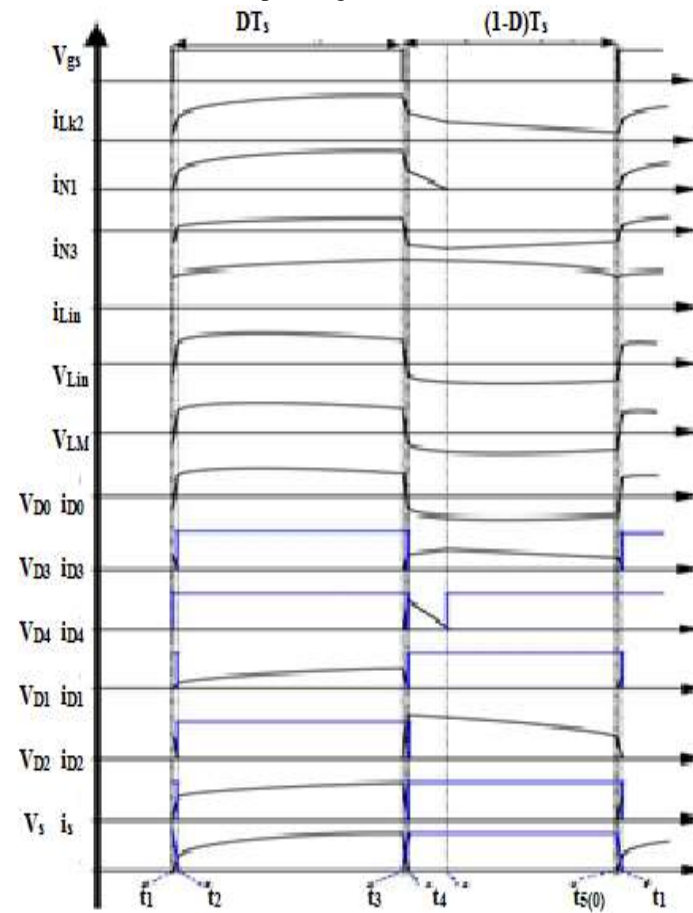


Fig. 8 Theoretical waveforms of proposed converter

### III. SIMULATION MODEL AND RESULTS

Simulation was obtained for a cascaded Couple Inductor- Reverse high step up converter using MATLAB/Simulink [R2014a] for input voltage 38v with R- load. Switching sequences have been provided using a pulse generator. Results were obtained for 38v to 380v.

The scheme of the block diagram describing a cascaded couple inductor- reverse high step up dc-dc converter is shown in fig.9 and the simulation parameters for different inputs are given in Table I. Fig.10 shows the simulation results for switching pattern generator. Fig.11 shows the simulation result of a cascaded couple inductor- reverse high step up dc-dc converter. Output of 280v obtained for an input of 28v, Fig. 12 shows the simulation result of a cascaded couple inductor- reverse high step up dc-dc converter. Output of 380v obtained for an input of 38v and Fig. 13 shows the simulation result of a cascaded couple inductor- reverse high step up converter. Output of 480v obtained for an input of 48v.

Table I. Simulation Parameters

Input Voltage=28v.

Parameter	As a High Step-Up Converter
Input Voltage	28v
Resistive Load	1MΩ
Output Voltage	280v

Input Voltage=38v.

Parameter	As a High Step-Up Converter
Input Voltage	38v
Resistive Load	1MΩ
Output Voltage	380v

Input Voltage=48v.

Parameter	As a High Step-Up Converter
Input Voltage	48v
Resistive Load	1MΩ
Output Voltage	480v

Performance comparison between the proposed converter and other converters:

The comparison between the previous results published in [2], [3] are compared with the results of the simulation development. In order to compare, the turns ratio of coupled inductor is the same that is  $n_2 = 1.5$  and  $n_3 = 1.5$ . Table II summarizes the voltage conversion gain, switch stresses, maximum diode stresses, maximum capacitor stresses, and numbers of components.

From the view of numbers of components, the numbers of components in the proposed converter are almost the same as that in [3]. The cost between them is almost equal. The numbers of components in the proposed converter are larger than that in [2]. This increases the cost of the proposed converter. Let us consider  $V_{in} = 38v$ ,  $V_o = 380v$ ,  $D = 0.3$ ,  $n_2 = n_3 = 1.5$  in Table II.

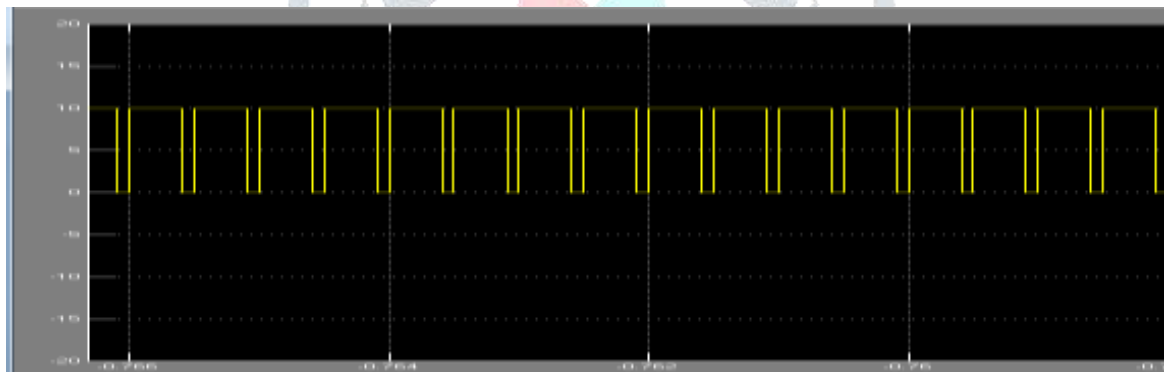


Fig.10 Simulation result for switching pattern generator.

Table III. Proposed Converter

Input Voltage	Output Voltage
28v	280v
38v	380v
48v	480v

From above TABLE III. that is proposed converter for different inputs, we can observe that by using a cascaded high step-up converter we can easily achieve output voltage 10 times more than the input voltage.

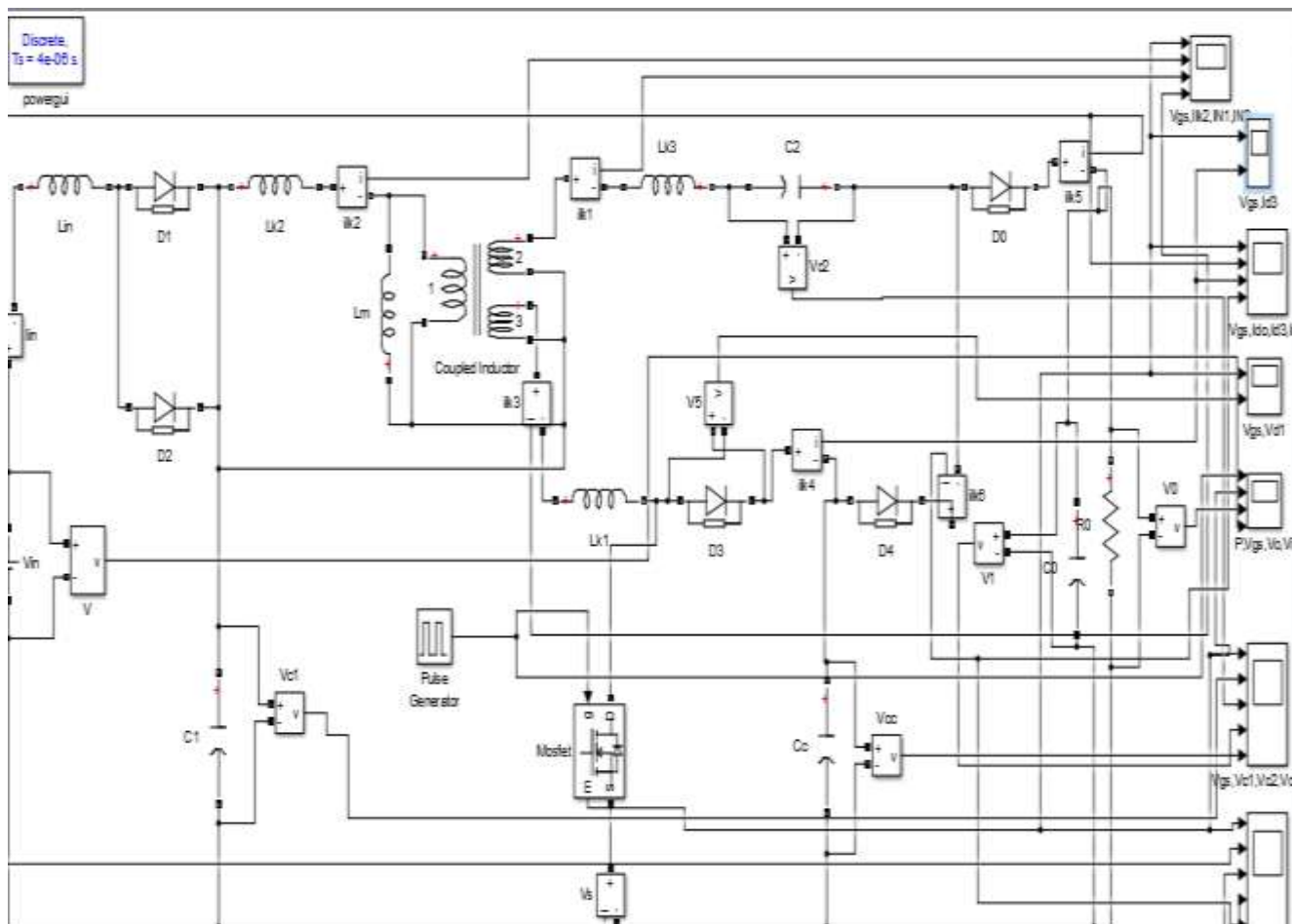


Fig.9. Simulation model of a cascaded couple inductor- reverse high step up dc-dc converter.

Pulse Generator=10V,  $V_{gs}$ , Input Voltage=28v. & Output voltage=280v.

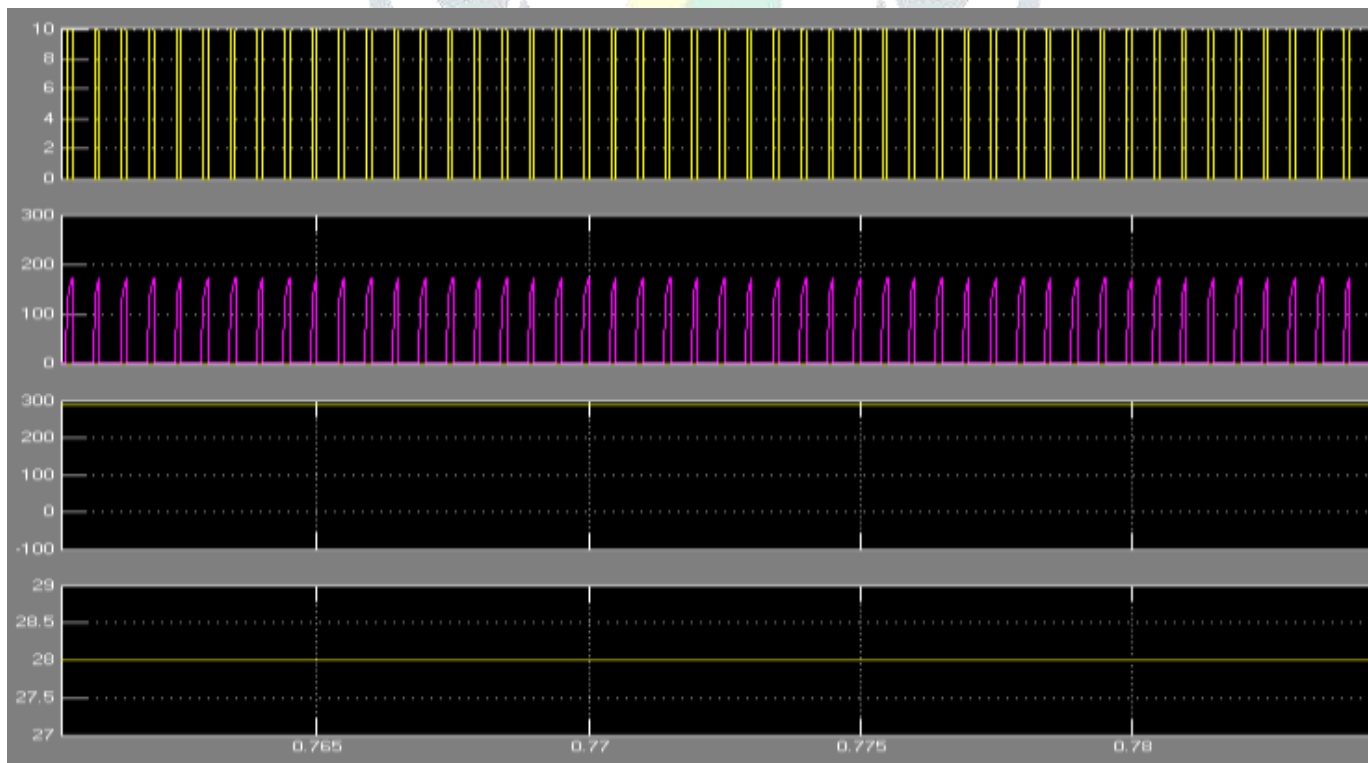


Fig.11 Simulation result of a cascaded couple inductor- reverse high step up dc-dc converter. Output of 280v obtained for an input of 28v.

Pulse Generator,  $V_{gs}$ , Input Voltage=38v. & Output Voltage=380v.

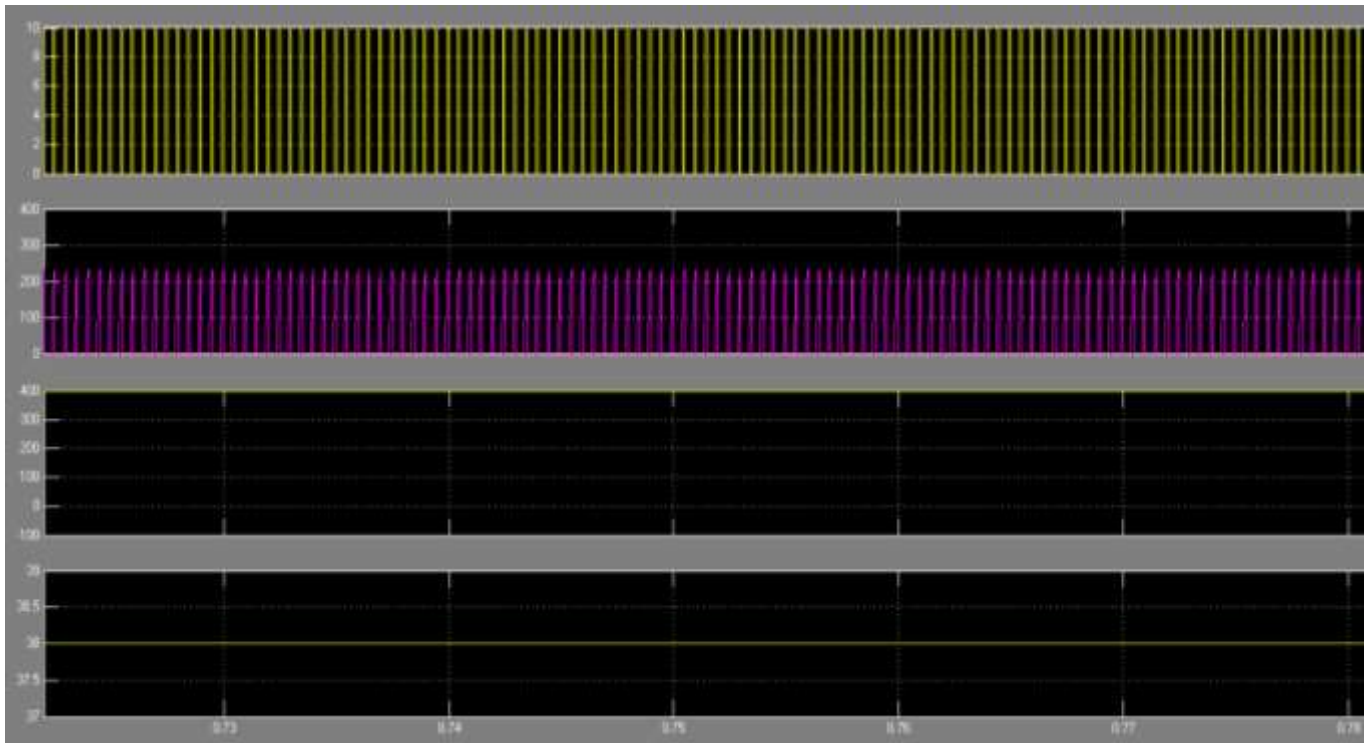


Fig.12 Simulation result of a cascaded couple inductor- reverse high step up dc-dc converter. Output of 380v obtained for an input of 38v.

Pulse Generator=10V,  $V_{gs}$ , Input Voltage=48v. & Output Voltage=480v.

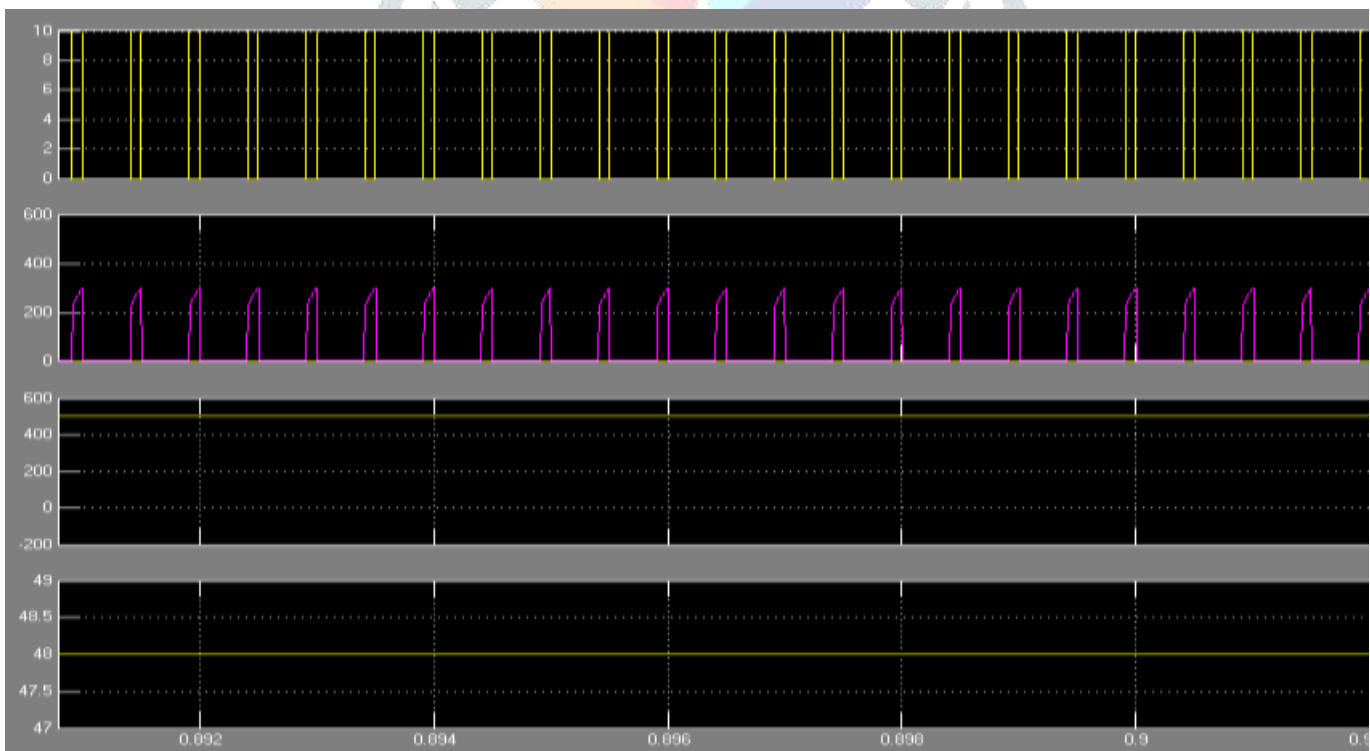


Fig.13 Simulation result of a cascaded couple inductor- reverse high step up dc-dc converter. Output of 480v obtained for an input of 48v.

Table II. Comparison Between Three Winding Coupled Inductor High Step-Up Converters [1]

Topology	Converter[2]	Converter[3]	Proposed converter
Voltage Gain	$(1 + n_3) + \frac{1 + Dn_2}{(1 - D)}$ =4.57	$n_2 + \frac{2 - D + n_3}{1 - D}$ =6.07	$\frac{1}{(1 - D)^2} \times \frac{2n_2 + n_3 - 1}{n_2 - 1}$ =14.28
Voltage stress of active switches	$\frac{V_o}{(1 + n_3)(1 - D) + 1 + Dn_2}$ =118.75	$\frac{V_o}{2 - D + (1 - D)n_2 + n_3}$ =89.41	$\frac{(n_2 - 1)V_o}{2n_2 - 1 + n_3}$ =54.85
Maximum Voltage stress of diodes	$\frac{(1 + n_3)V_o}{(1 + n_3)(1 - D) + 1 + Dn_2}$ =296.87	$\frac{(1 + n_2)V_o}{2 - D + (1 - D)n_2 + n_3}$ =223.52	$\frac{(n_2 + n_3)V_o}{2n_2 - 1 + n_3}$ =325.71
Maximum Voltage stress of capacitors	$\frac{(1 + n_3)(1 - D)V_o}{(1 + n_3)(1 - D) + 1 + Dn_2}$ =207.81	$\frac{(1 + n_2)(1 - D)V_o}{2 - D + (1 - D)n_2 + n_3}$ =156.42	$\frac{(n_2 + n_3 - D(n_3 + 1))V_o}{(n_2 - 1)(2n_2 - 1 + n_3)}$ =488.57
Number of capacitors	3	4	4
Number of diodes	3	4	5

#### IV. CONCLUSION

In this work, modeling and simulation of a cascaded couple inductor- reverse high step up converter has been developed using MATLAB/simulink [R2014a]. Simulation results were observed to confirm the predicted performance of the proposed topology. The developed simulation results are obtained for resistive load. Because, the resistive load has been used to reduce the complexities of the circuit. Under this loading condition, the converter's performance has been tested for an input voltage 28v, 38v and 48v then we observed an output voltage as 280v, 380v and 480v. The MOSFETs are used as the main power switching device due to its high power applications and fast switching frequency for fine control.

For the high step-up applications, a novel high voltage gain converter is introduced in this work, which combines a quadratic boost converter with three-winding coupled inductor and diode- capacitor techniques. The diode-capacitor circuits not only increase the voltage conversion gain, but also recycled the leakage energy to the output. The three-winding coupled inductor-reverse makes the smaller turn's ratio available implementing the high voltage conversion gain. Due to the cascaded structure, a smaller duty cycle can produce a high conversion gain. The voltage stresses on the power switch and diodes are very low. The efficiency is improved efficiently as compared to the results published in previous papers [2], [3].

#### REFERENCES

1. Fei Li and Hongchen Liu, "A Cascaded Coupled Inductor-Reverse High Step-Up Converter Integrating Three-Winding Coupled Inductor and Diode-Capacitor Technique," *IEEE transactions on industrial informatics*, vol. 13, no. 3, june 2017.
2. R. J. Wai, C. Y. Lin, R. Y. Duan, and Y. R. Chang, "High-efficiency DC-DC converter with high voltage gain and reduced switch stress," *IEEE Trans. Ind. Electron.*, vol. 54, no. 1, pp. 354-364, Feb. 2007.
3. K. C. Tseng, J. T. Lin, and C. C. Huang, "High step- up converter with three-winding coupled inductor for fuel cell energy source applications," *IEEE Trans. Power Electron.*, vol. 30, no. 2, pp. 574-581, Feb.2015.
4. Y. Deng, Q. Rong, W. Li, Y. J. Shi, and X. He, "Single-switch high step-up converters with built-in transformer voltage multiplier cell," *IEEE Trans. Power Electron.*, vol. 27, no. 2, pp. 3557-3567, Aug. 2012.



5. Q. Li and P. Wolfs, "A review of the single phase photovoltaic mod-ule integrated converter topologies with three different DC link configurations," *IEEE Trans. Power Electron.*, vol. 23, no. 3, pp. 1320–1333, May 2008.
6. R. J. Wai and R. Y. Duan, "High step-up converter with coupled-inductor," *IEEE Trans. Power Electron.*, vol. 20, no. 5, pp. 1025–1035, Sep. 2005.
7. Y. P. Hsieh, J. F. Chen, T. J. Liang, and L. S. Yang, "Novel high step up dc-dc converter with coupled-inductor and switched-capacitor techniques," *IEEE Trans. Ind. Electron.*, vol. 59, no. 2, pp. 998–1007, Feb. 2012.
8. E. S. Da Silva, L. Dos Reis Barbosa, J. B. Vieira, L. C. De Freitas, and V. J. Farias, "An improved boost PWM soft-single-switched converter with low voltage and current stresses," *IEEE Trans. Ind. Electron.*, vol. 48, no. 6, pp. 1174–1179, Dec. 2001.
9. C.-T. Pan and C.-M. Lai, "A high-efficiency high step-up converter with low switch voltage stress for fuel-cell system applications," *IEEE Trans. Ind. Electron.*, vol. 57, no. 6, pp. 1998–2006, Jan. 2010.
10. Y. P. Hsieh, J. F. Chen, T. J. Liang, and L. S. Yang, "A novel high step-up DC–DC converter for a microgrid system," *IEEE Trans. Power Electron.*, vol. 26, no. 4, pp. 1127–1136, Apr. 2011.
11. S. M. Chen, T. J. Liang, L. S. Yang, and J. F. Chen, "A cascaded high step-up DC–DC converter with single switch for microsource applications," *IEEE Trans. Power Electron.*, vol. 26, no. 4, pp. 1146–1153, Apr. 2011.
12. X. Hu and C. Gong, "A high voltage gain DC-DC converter integrating coupled-inductor and diode-capacitor techniques," *IEEE Trans. Power Electron.*, vol. 29, no. 2, pp. 789–800, Feb. 2014.

